

Features

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery

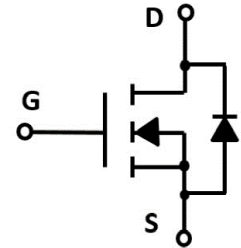
V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
150V	170mΩ@10V	5A
	250mΩ@4.5V	

Application

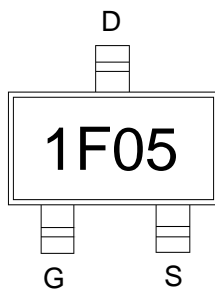
- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor



SOT-23 view



Schematic diagram



1F05: Device code

Marking and pin assignment



Pb-Free



RoHS



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	150	V
V_{GS}	Gate-Source Voltage	±20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 5	A

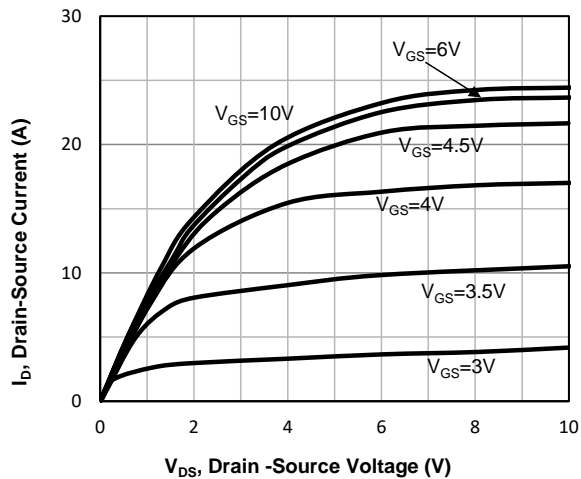
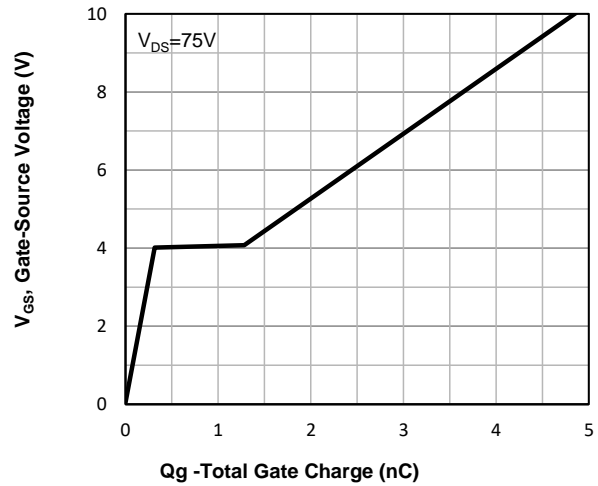
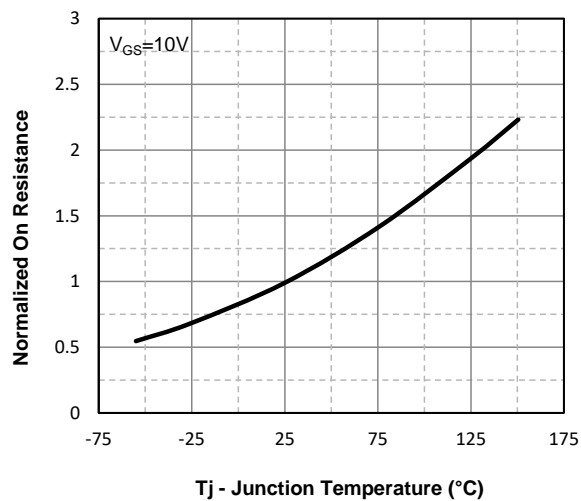
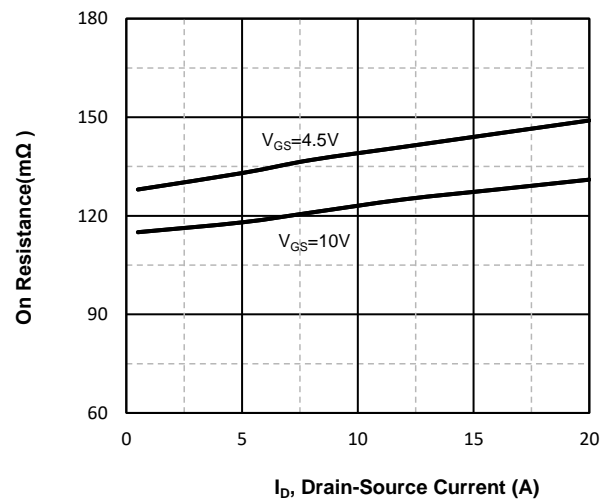
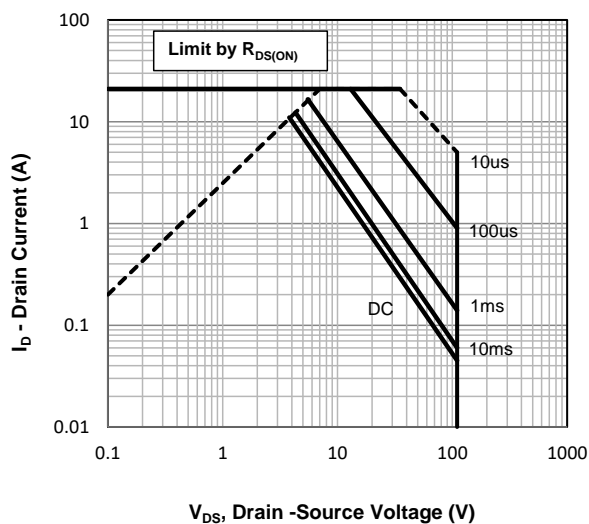
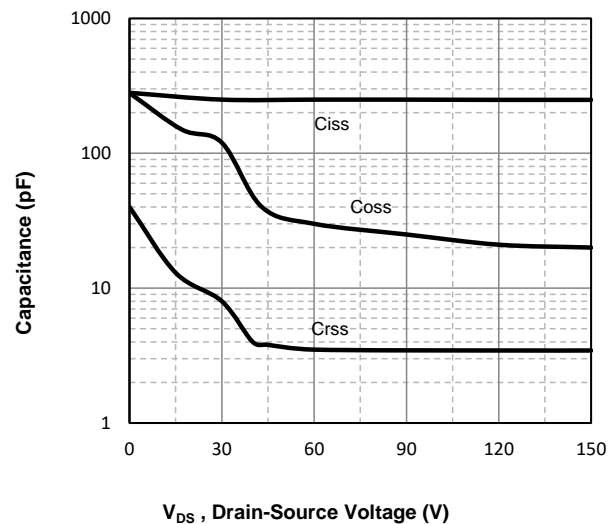
Mounted on Large Heat Sink

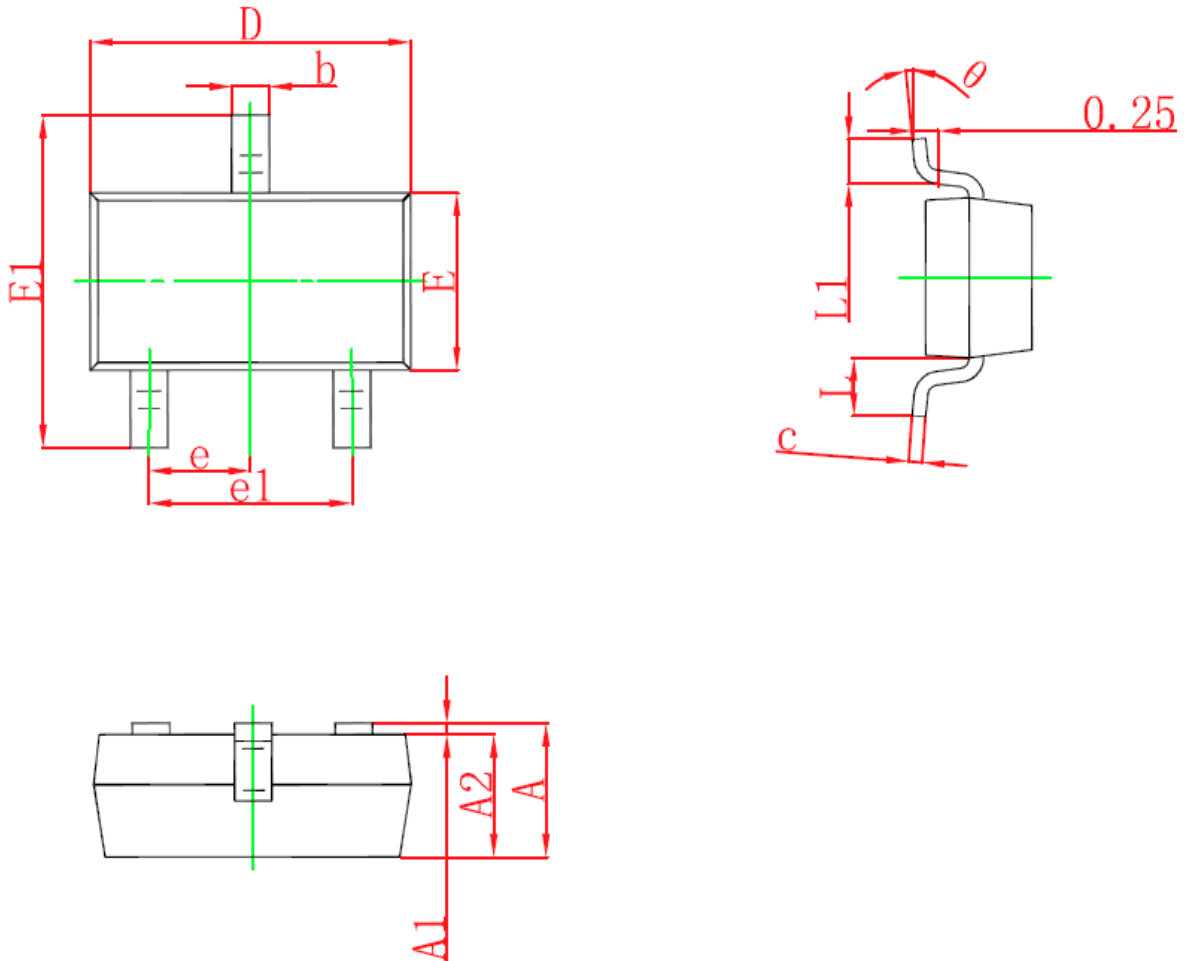
I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ 20	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ 5	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 41.6	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	50	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLS1F05	SOT-23	1F05	3,000	45,000	180,000	7"reel

Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	150	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =150V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.5	--	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =5A	--	115	170	mΩ
		V _{GS} =4.5V, I _D =3A	--	130	250	mΩ
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =75V, V _{GS} =0V, f=1MHz	--	245	--	pF
C _{OSS}	Output Capacitance		--	27	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	3.6	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DS} =75V, I _D =10A, V _{GS} =10V	--	4.9	--	nC
Q _{gs}	Gate Source Charge		--	0.3	--	nC
Q _{gd}	Gate Drain Charge		--	0.9	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =75V, I _D =10A, V _{GS} =10V, R _G =6Ω	--	3.1	--	nS
t _r	Turn-on Rise Time		--	2.7	--	nS
t _{d(off)}	Turn-Off Delay Time		--	7.9	--	nS
t _f	Turn-Off Fall Time		--	2	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =5A	--	--	1.2	V

Typical Operating Characteristics

Fig1. Typical Output Characteristics

Fig2. Typical Gate Charge Vs. Gate-Source Voltage

Fig3. Normalized On-Resistance Vs. Temperature

Fig4. On-Resistance Vs. Drain-Source Current

Fig5. Maximum Safe Operating Area

Fig6 Typical Capacitance Vs. Drain-Source Voltage

SOT-23 Package information


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°